





68 99/3692 4

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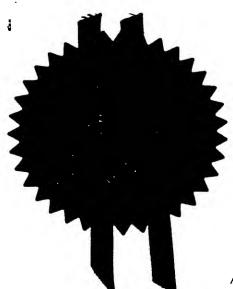
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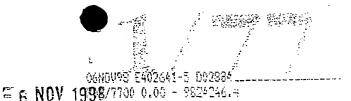
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9824246.4

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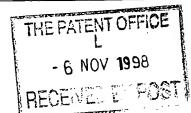
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1. Your reference

P22886/CMC/GWO

- 2. Patent application number (The Patent Office will fill in this part)
- 3. Full name, address and postcode of the or of each applicant (underline all surnames)

Kelsill Limited 12 Finch Road Douglas Isle of Man IM1 2SA



Patents ADP number (if you know it)

If the applicant is a corporate body, give the country/state of its incorporation

07319312 cc.1.

4. Title of the invention

"Electronic Circuit"

5. Name of your agent (if you bave one)

Murgitroyd & Company

"Address for service" in the United Kingdom to which all correspondence should be sent (including the postcode)

373 Scotland Street GLASGOW G5 8QA

Patents ADP number (if you know it)

1198013

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Country

Priority application number (if you know it) Date of filing
(day / month / year)

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Number of earlier application

Date of filing
(day / month / year)

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  - a) any applicant named in part 3 is not an inventor, or
  - there is an inventor who is not named as an applicant, or
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yes

# Patents Form 1/77

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11.

I/We request the grant of a patent on the basis of this application.

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Date 05.11.1998

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Graham Wotherspoon 0141 429,2200

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1 ELECTRONIC CIRCUIT 2 3 This invention relates, in one aspect, to a novel electronic detection circuit and materials for use 5 The invention relates in other aspects to 6 circuits, materials and techniques relating to security 7 printing. 8 9 The present invention in its broadest sense is 10 concerned with the provision of security in relation to documents, vouchers, packaged goods and tokens of 11 12 Examples of these are banknotes, cheques and 13 drafts, bond and stock certificates, and credit and bank cards. 14 All of these are referred to hereinafter for simplicity as "documents". 15 16 17 Documents of this nature have the requirement to be as 18 secure as possible against forgery and falsification 19 and for this purpose it is desirable that they exhibit 20 both covert and overt security features. 21 expression "covert security feature" is used to denote some security feature which is not visually apparent to 22 23 the normal user, whereas "overt security feature" is 24 used to denote a feature which can be readily seen and

recognised by members of the public without the use of

specialised equipment or confidential information.

Traditional forms of overt security features include

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1 water marks, metal security threads, and the use of 2 specialised forms of paper and printing. 3 4 Known methods of covert security include NIR and IR absorber inks, magnetic threads, complex optical and 5 6 electrically conductive indicia, anti-Stokes, visiblewavelength-emitting phosphors etc. 7 8 9 With rapid advances in reprographic technology such as 10 relatively cheap and high quality colour photocopiers 11 and easily available digital image manipulation, the 12 traditional forms of security have become increasingly 13 easy to circumvent. There is accordingly a requirement 14 for improved forms of both covert and overt security 15 features, preferably ones which can be used with 16 existing printing technology at modest cost. 17 18 According to one aspect of the present invention, there 19 is provided a method of providing a document with a 20 covert security feature, in which the document is 21 printed using an ink containing a dopant, the dopant 22 being of a material which can be identified by 23 examination of its response to visible wavelength 24 photon radiation. 25 26 This and other aspects and features of the present 27 invention are defined in the appended claims. 28 29 The use of light emitting (inorganic and organic) 30 dopants, either in straight emission mode, Anti-Stokes, 31 IR shifting etc is well known in the prior art, and is 32 commonly practised by using powdered inorganic solids 33 with printing inks. Prior art also exists for doping 34 with unstructured absorbers, such as carbon black. 35

36 What is not known in the prior art is to design

1 inorganic, or organic, dopants with absorption spectra 2 sufficiently different in form and structure from the 3 absorption spectra of printing inks so that the dopants 4 can be easily identified. They thus become very covert 5 because they exhibit no UV, visible or IR stimulated 6 output to be observed by a counterfeiter. 7 preferred elements for our dopants can be fused with 8 other elements in order to hide the presence of the 9 dopant element, or to alter its absorption spectrum; or 10 the oxide or salt of preferred element itself can be 11 directly mixed into, for example, a printing ink or a 12 batch composition for plastics production etc. 13 the dopant is mixed with other elemental compounds we 14 have shown that, provided one of its admixture compounds contains a substantial proportion by weight 15 16 of a light atomic number (z) element, varying the 17 proportion of this compound in the final mix can vary the absorption spectrum of the find inorganic mixture, 18 19 thus essentially creating further dopants.

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Visible wavelength light authentication of documents in known in the prior art but only in terms of determining the reflection or transmission spectrum of the natural materials of the documents. Such techniques frequently use filters or beam splitters in sets. Such systems suffer from low processing speed, poor optical resolution and hence provide relatively poor security, and are subject to variations in the printed material under examination. Our system depends on the incorporation of a synthesised inorganic dopant into or onto the document at any stage of its manufacture, including the printing stage. These dopants are designed to have very complex visible wavelength absorption spectra, measured in either reflective or transmissive mode. The spectra they exhibit are not found in printing inks or common marbling substrates.

This results in high signal-to-noise ratio detection, and hence the ability to identify the dopant in 10msec or less using low output (c. 4W) bulbs as illuminants. The dopants also exhibit complex low (10-60 keV) energy electron excitation spectra which allows sub-surface detection of the dopants which will be described later. The dopant incorporation with its unique spectrographic pattern gives independence from document soiling, wear and tear etc, because it allows excellent signal-tonoise ratio. Pattern recognition software to identify, within 1 msec, the complex signature of our synthesised dopants is readily available from suppliers in the public domain, having been used in optical and nuclear spectrometry for 30 years. Our dopants can be incorporated singly, mixed, or in separate areas to produce a bar code, or to simply confuse a forger. The

dopants, depending on composition, are either

colourless or transparent, or coloured, at the choice

of the user.

For visible wavelength interpretation the preferred method is to illuminate an area of at least 5mm² by a ring of 6-8 200µ optical fibres in a concentric ring, and channel reflected light through an inner 200µ optical fibre to the wavelength detector. This, eliminates the optical losses due to lenses in much prior art, which in turn leads to the processing speed of our system. CCD based wavelength detectors, followed by A-D conversion for processing are standard technologies in public domain electronics. Our dopants are engineered to give no visible signal, such as fluorescence, upon illumination by UV, visible, or IR radiation and are hence not easily replicated as has happened with fluorescent inks, and other emitting technologies.

Standard printing inks, or colourisers in plastics etc, give relatively unsophisticated reflectance spectra -see for example Figures 1, 2, 3 which show the visible reflectance spectrum of a Pantone standard blue, green and red ink from a paper print. Compare these with Figures 4, 5, 6, 7 which show the visible reflectance spectrum from four of our dopants incorporated in a clear litho varnish and printed on the same paper. These prints are completely colourless to the eye. Figure 4 for example shows many easily identifiable peaks, troughs and turning points in its spectrum with a shape easily distinguished from any ink or colouring It is these unique features which gives the excellent signal-to-noise ratio, giving the rapid identification ability of our system, with excellent identification rates, and very low false acceptances, together with high rejection for forged copies.

The features, and/or slopes, of the reflectance spectra can be shifted to create other dopants by incorporating the dopants into inorganic compounds of the type described later.

The use of visible wavelength spectrometry, as opposed to IR or NIR wavelengths, makes possible many more commercial applications. This is firstly because of the reduced cost of components for the visible, and secondly because the cheapest excitation source is a common (4W) torch bulb which emits plenty of visible light but very little IR. Hence IR and NIR techniques require more powerful and costly excitation sources. Also by moving to the visible we make it easy to construct simple hand-held portable instrumentation which again increases possible commercial applications.

Visible wavelength spectroscopy as revealed in the

1 prior art with application to security uses lenses or 2 mirrors and lamps to provide the illumination source. 3 4

Many suppliers, such as Oriel Corp. USA, now make commercially available reflectance probes which are about 6mm diameter overall and contain a ring of illuminating fibres (200µ diameter 5-8 in number) surrounding a centre core of detecting fibres. Use of these probes gives much improved signal-to-noise ratio at the CCD array, or Si photodiode array, or other Using other off-the-shelf components the output of the array spectrometer can be coupled to D-A converters and operated from a laptop, hand-held palmtop, or desktop PC computers. This can easily be

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15 interfaced to standard computer software on production

16 lines for authentication at high speed - 10m/sec.

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It is the ready availability of these fibre probes which has made our high speed absorption spectroscopy possible.

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The standard commercial concentric fibre reflectance probes available in the market place have a major drawback in that they require to be placed in contact, or very nearly in contact. For high speed monitoring this gives real problems in object positioning. optimum would be a fibre probe capable of operating well, yet be 10mm away.

28 29

30 To achieve this is not simple, because the collected 31 light from the sample has to pass through an entrance 32 slit at the spectrometer, this slit being typically  $250\mu$  tall x  $100-200\mu$  wide. 33 The point is this is a 34 rectangle, not a circle, so coupling to fibres efficiently is not simple. The basic probes ignore 35 36 this.

We have arrived at a method of producing the optimal solutions.

As far as illumination is concerned, the standard stable commercial lamp housings in the range 4-140w of visible light terminate in fibre bundles typically of 0.39NA (NA=1/2f). The outer concentric ring of fibres is an optimum design needs to match to this NA, so in this example there is only one optimal choice,  $400\mu$  0.39NA fluorinated acrylate clad silica core fibre.

As far as collection of reflected signal light is concerned standard practice is to consider the optics at the signal end. This is not correct. The whole design of the inner concentric light collecting fibre/fibres in our reflectance probe is dependent on optimising the light collection at the spectrometer. Typically miniature CCD/PDA card spectrometers have focal depth f=2.27, so their NA=0.22. For true optimal signal light delivery one is then immediately forced to use Si/Si fibre (silica core, silica clad) because its NA=0.22, a perfect optimal match.

By choosing  $100\mu$  NA=0.22 Si/Si, we then form bell-end lenses on the signal collection end of each signal collecting fibre. This increases the NA to 0.3 at the ends, giving a 5mm diameter collecting spot for a 1cm stand-of of our optimum probe for reflectance measurements.

The methodology we have described gives a factor of 10 increase in signal delivered to the spectrometer and this is commercially very significant in terms of the performance of equipment in authentication, giving much improved un-ambiguity in decision making.

1 Current design of spectrophotometer are all air-spaced: the imputs, mirrors, slits are all separated by air 2 3 This leads to light loss inefficiency and sizeable units. Designs are available in the prior art for plastic-spaced spectrometers in which an input 6 fibre is coupled to a thin plastic rectangle with a diffraction granting etched/cut into one end (cf 7 8 Microports GmbH). These types suffer from the problems 9 They only work in the visible, due to the 10 UV and IR absorption in plastic. They have focus problems due to the low refractive index of all 11 12 plastics compared to glass. 13 14 Our design eliminates these disadvantages by making a 15 solid state spectrometer (about 1"x1"x5mm) out of a 16 machined block of glass. The grating is 17 etched/machined into one end. Variable refractive 18 index glass can be used to ensure total internal reflection at the top faces. 19 20 The edges can be coated black to eliminate serious 21 interfering reflections, or a plastic coating of 22 refractive index lower than the glass can be sprayed on 2.3 24 the edges. The higher refractive index of glass, its 25 optical purity, and its composition can easily permit 26 spectrum in the UV, visible and the IR. 27 28 It is more compact because of the higher refractive index of glass, permitting more applications of our 29 30 dopant technology. The principle is sketched in Fig 31 12, and can be mass produced cheaply. The spectrometer 32 body can be made from a slice of synthetic fused silica 33 allowing use in the UV down to 250nm, as well as in the 34 visible, and out to  $2.4\mu$  in the IR before the first 35 absorption peak in silica occurs.

The invention also provides a method of providing a 1 2 document with a covert security feature by use of a 3 dopant which gives a characteristic response to low energy electron irradiation. 4 5 6 An inspection system for use in the electron probe 7 method comprises a source of low energy electron radiation, said source being positioned to irradiate a 8 9 document in a predetermined location, a detector positioned to view a document at said location, and 10 11 processing electronics connected to the detector to 12 assess the presence or absence of a selected dopant or 13 This electron detection system is sketched in 14 Figs 8 and 9. 15 16 In one suitable form, the radiation source and detector 17 may be mounted in a housing having a common window to which the document may be offered. 18 19 20 A suitable electron detector is a fast Si-PIN 21 photodiode, as is readily available. A suitable photon 22 detector is a CCD, PIN photodiode or photomultiplier. 23 24 For sub-surface incorporation of our dopants, giving 25 added security, low energy surface-penetrating electron 26 radiation, typically 10→100keV, can be used. 27 dopants to match this interrogation system are for 28 example based on oxides or salts, of germanium. 29 niobium, strontium, copper, nickel, iron, cobalt, 30 chromium, selenium, lead, zinc, boron, cadmium, 31 maganese, tungsten or vanadium. The electron probe 32 radiation may suitably be provided by conventional low 33 voltage electron guns, or from active source material such as  $Cd^{109}$ ,  $Fe^{55}$ ,  $Am^{241}$  or  $Bi^{207}$ . 34 35

Fig. 8 shows a typical electron probe geometry, Fig 9

1 shows typical circuitry, and Fig 10 shows a typical 2 dopant spectrum from Cd109 probing of a paper print at 3 30% dopant concentration, by weight, in a 1µ thick ink film. 4 5 6 The detector is typically a fast Si-PIN photodiode with 7 a vacuum tight thin window - many types of these are 8 readily available commercially. 9 10 The doped area can be any suitable area of product to 11 be examined. For high speed applications, such an area 12 might well be of the order of 60 mm long x 5 mm wide to 13 allow good data access time by integration when, for 14 example, a banknote passes through detector at high 15 speed, say within a time of 10 millisecond. 16 17 The detection philosophy for sub-surface electron 18 interrogation is that of beta/electron backscatter 19 (where for example a monoenergetic beta source such as 20 Bi<sup>207</sup> exhibits clear backscatter peaks from our 21 dopants), or low energy X-ray fluorescence emission 22 from shell electrons of dopants stimulated by a low 23 energy photon source, such as Fe<sup>55</sup>. 24 25 Typical detector circuitry (Figure 9) is shown purely 26 for illustration, and falls for choice into one of two 27 types, either (a) full PHA, pulse height analysis 28 spectral display, or (b) low level single or multiple 29 discriminator windows and a counter, giving rapid 30 identification of dopant presence in a few digital 31 channel peaks, once only a few counts are recorded in 32 each spectral window. These detection methodologies 33 are standard practice in the art, see for example "Radiation Detection and Measurement" by Glenn F Knoll, 34 35 Wiley & Sons, ISBN 0-471-49545. These detection 36 methodologies are cheap and readily available.

1 The dopants we have identified as working well can be 2 added, as is well known in the art, to standard offset litho printing inks, in quantities up to about 30% by 3 4 volume without affecting the printing process, 5 providing the dopants we shall describe have been 6 micronised into fine powders of the order of  $1-4\mu$ 7 diameter. If this step is omitted poor uniformity 8 printing results. Our dopants need add no colour to 9 the ink, so give a colourless invisible printed strip 10 onto the object to be protected. Alternatively a 11 colouring dopant can be selected to blend in with an 12 existing coloured scheme.

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A major advantage of our technology is that our dopants are cheap and simple, not requiring the presence of complex expensive chemicals.

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The dopants can be applied to artefacts by any standard deposition technique - air spray, lacquering, printing, stamping.

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The dopants could also be directly incorporated into paper or plastic (for example) at time of manufacture of said paper or plastic. For our techniques to work it is not necessary that the dopants are added as a superior layer or film, although in many cases this will be the simplest and cheapest method. that our dopant/excitation/detector technology does not require surface deposition can offer more security/covertness to the process. It arises because the excitation methods we are employing have ranges of many tens of microns in common materials such as paper and plastics. The fact that our dopant need not be on the surface denies the forger the opportunity to scrape off samples from repeated small surface areas and

36 analyse them to look for "surprising" changes in

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composition from area to area.
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                                            Such changes give him a
 2
      clue that covert technology is being used in that area.
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 4
      Purely for illustration of our claim, we list the
      following suitable dopants which all work well by
 5
      electron probing in the manner we have described.
 6
 7
      know our methodology can be applied by utilising many
 8
      other dopant species:-
9
10
      ZnO
                  zinc oxide
11
                  barium sulphate
      BaSo<sub>4</sub>
12
      BaCO<sub>3</sub>
                  barium carbonate
13
                  barium oxide
      BaO
14
      BiCl<sub>3</sub>
                  bismuth chloride
                  bismuth oxide
15
      Bi_2O_3
16
      CdO
                  cadmium oxide
17
      Gd_2O_3
                  gadolinium oxide
18
       In_2O_3
                  indium oxide
19
                  lanthanum oxide
      La_2O_3
20
      PbCO<sub>3</sub>
                  lead carbonate
21
      PbO
                  lead monoxide
22
      Pb_2O_3
                  red lead oxide
23
      MqO
                  magnesium oxide
24
      MnO
                  manganese oxide
25
      MOO3
                  molybdenum oxide
26
       NiO
                  nickel oxide
27
       SrCO3
                  strontium carbonate
                  strontium oxide
28
       SrO
29
                  tantalum oxide
       Ta_2O_3
30
       SnO<sub>2</sub>/SnO
                  tin oxide
31
       TiO2
                  titanium oxide
32
       WO_3
                  tungsten oxide
33
       Ge0,
                  geranium oxide
34
                  vanadium oxide
       V_2O_5
35
       Na<sub>2</sub>CO<sub>3</sub>
                  sodium carbonate
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potassium carbonate

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 $K_2CO_3$ 

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lithium carbonate
1
     Li<sub>2</sub>CO<sub>3</sub>
      RbCl
 2
                rubidium chloride
 3
      SC_2O_3
                scandium oxide
     Ta_2O_3
                Tantalum oxide
 5
      TeO,
                tellurium oxide
 7
      The multiple peaks, troughs, and turning points
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      resulting give rapid, positive, unambiguous
      identification of dopant presence (and hence object
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      authenticity) and allow multiple dopants to be used as
      a further method of disguise, if required.
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      The detector itself is a simple Si-PIN photodiode,
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      typically, available from many suppliers.
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      Figure 8 shows one form of detector head which may be
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      used with the circuit of Figure 9, with a source and a
18
      detector housed in a common housing and working via a
19
      common window.
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      Our technique of low voltage electron or visible
22
      wavelength photon interrogation of the doped sample
23
      means that high detection efficiency (and hence good
24
      statistical data output for unambiquous dopant
25
      identification) is easily achieved even with small,
26
      thin, silicon photodiode detectors.
27
28
      Figure 11 shows the efficiency of silicon detectors.
29
      The high efficiency at low electron energies is highly
      relevant to achieving good detection rates, and
30
31
      controls the sources which are usefully employed.
32
33
      In the preparation of the inorganic powders for doping
34
      to permit identification by visible light wavelengths
35
      we arrived at these by not limiting ourselves to
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      chemical compounds which could be formed by
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precipitation from a solution - because such compounds 1 2 Rather we found the most are limited in numbers. 3 useful compounds (those with the most distinctive 4 absorption spectra in the visible) could be formed by 5 fusion melting. We found using silicates, phosphates, borates to be the most useful starting points for the 6 7 fusion, because they give transparent matrices. 8 9 In forming the required solids for powdering, the 10 chemical batch composition is not, for example, limited 11 to that required to produce, say, a glass. 12 because long range atomic order is not required in the 13 solid, since homogeneity is assured by the micronising. 14 Indeed in general terms we have found that the best 15 compositions are obtained where phase separation of the 16 melt temperature is imminent. This point is determined 17 experimentally for each composition. Nor need the 18 chemistry be limited to stoichometric ratios such as to 19 arrive at crystalline compounds, eg as used to produce 20 the commonplace inorganic fluorescence powders added to 21 printing inks. 22 23 In many compositions, the structure and magnitude of 24 the absorption peaks can be controlled over a wide 25 range by control of the gas atmosphere during the melt 26 Again this needs to be established by trial and 27 error for each composition - essentially by test 28 melting each composition in air, in a reducing 29 atmosphere, and in an oxidising atmosphere to determine 30 the optimum methodology for the absorption profile required. 31 32 33 In many compositions, the structure and magnitude of 34 absorption peaks can be controlled by including a 35 substantial quantity (>20% by weight) of a high Z 36 element in the batch composition (lanthanum, bismuth,

and strontium work well, as examples). Then varying 1 the content of this high Z element only gives changes 2 3 in position and magnitude of the absorption peaks. 5 We have shown our dopant technology to work in a wide variety of compounds, including, but not limited to, 6 7 silicates, borosilicates, borates and germanates. interesting and suitable composition is of the type 40-8 9 56wt%  $SiO_2$ , 5-35wt%,  $La_2O_3/Bi_2O_3/Sr_2O_3$ , 2-14wt%  $\text{Li}_2\text{O}/\text{K}_2\text{O}/\text{Na}_2\text{O}$ , 0-6%  $\text{Al}_2\text{O}_3$  wherein the La, Bi, Sr are 10 examples of a suitable high Z component. 11 12 13 Another suitable composition is of the type SiO<sub>2</sub> 51wt%, B<sub>2</sub>O<sub>3</sub> 13wt%, Al<sub>2</sub>O<sub>3</sub> 8wt%, MgO 6wt%, CaO 10wt%, BoO wt%, SrO 14 4wt%, ZnO 4wt%. Ths is particularly suitable as a base 15 for incorporating dopants for visible wavelength 16 absorption detection because all the base elements have 17 18 largely unfeatured absorption spectra. 19 20 Incorporation all three alkaline earth, plus BoO, gives 21 much reduced melting temperatures.

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1	Table 1					
2						
3	Preferred element	in	dopants	for	electron	probing
4	system					
5						
6	chromium					
7	vanadium					
8	iron					
9	caesium					
10	molybdenum					
11	nickel					
12	tungsten					
13	terbium					
14	samarium					
15	praesodymium					
16	neodymium					
17	holmium					
18	selenium					
19	rhenium					
20	thulium					
21	ruthenium					
22	zinc					
23	bismuth					
24	lead					
25	tin					•
26	titanium					
27	sodium					
28	potassium					
29	europium					

1	Table 2					
2						
3	Preferred elements for do	ppant fabrication for visible				
4	wavelength absorption system					
5						
6	zinc					
7	barium					
8	lanthanum	samarium				
9	lead	praesodymium				
10	magnesium	europium				
11	strontium	boron-10				
12	tin					
13	titanium	neodymium				
14	chromium	holmium				
15	iron	thulium				
16	caesium	cadmium				
17	molybdemum	antimony				
18	nickel	erbium				
19	tungsten	lutecium				
20	cobalt					
21	sodium					
22	potassium					
23	terbium					
24						
0.5						

### CLAIMS

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1. A method of providing a document with a covert
security feature in which the document is provided
with at least one dopant, the dopant being of a
material which can be identified by examination of
its response to visible wavelength photoz
radiation.

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10 2. The method of claim 1, in which the dopant
11 comprises one or more of the elements listed in
12 Table 2, in elemental form or as an oxide or salt.

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A document provided with a covert security feature
 by the method of claim 1 or claim 2.

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17 4. A method of examining a document according to
18 claim 3, in which the document is illuminated with
19 broad-band visible light, and the resulting
20 spectrum is compared with a known spectrum.

21.

The method of claim 4, in which said comparison is carried out by pattern recognition techniques.

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25 6. The method of claim 4 or claim 5, in which the
26 document is examined using a reflectance probe
27 having a ring of illuminating fibres surrounding a
28 central core of electing fibres.

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30 7. A reflectance probe for use in the method of claim 6, in which the illuminating fibres consist of 400 $\mu$ , 0.39NA fluorinated acrylate clad silica core fibre, preferably between 5 and 8 fibres in number.

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36 8. The probe of claim 7, in which the detecting

1 fibres are  $100\mu$ , 0.22NA silica core, silica clad 2 fibres formed with bell-end lenses to give 0.3NA at the collecting end. 3 4 A solid state spectrometer, comprising a machined 5 9. 6 block of glass having a diffraction grating 7 machined or etched at one end, and having an 8 optical input and a detector located at an 9 opposing face. 10 11 10. The spectrometer of claim 9, in which the glass is fused silica. 12 13 14 11. The spectrometer of claim 9 or claim 10, in which 15 the detector is a CCD array secured to the face of the glass block. 16 17 18 12. A method of providing a document with a covert 19 security feature, in which the document is 20 provided with at least one dopant, the dopant 21 being of a material which can be identified by 22 examination of its response to low energy electron 23 radiation. 24 25 13. The method of claim 12 in which the dopant. 26 comprises one or more of the elements listed in 27 Table 1, in elemental form or as oxide, carbonate 28 or sulphate. 29 30 14. A document provided with a covert security feature 31 by the method of claim 12 or claim 13.

32

15. A method of examining a document according to 34 claim 14, in which the document is irradiated with 35 low energy electrons.

1 16. The method of claim 15, in which the electron radiation has an energy between 10keV and 100keV.

3

4 17. An inspection system for use with the method of 5 claim 15 or claim 16, comprising a source of low 6 energy electron radiation, said source being 7 positioned to irradiate a document in a 8 predetermined location, a detector positioned to 9 view a document at said location, and processing 10 electronics connected to the detector to asses the 11 presence or absence of a selected dopant or 12 dopants.

13

14 18. The inspection system of claims 17, in which the detector is a fast Si-PIN photodiode.

16

17 19. The method of any of claims 1, 2, 12 or 13 in
18 which the or each dopant is micronised into a fine
19 powder, preferably 1-4μ diameter, before being
20 incorporated in a printing ink, lacquer or other
21 suitable carrier.

22

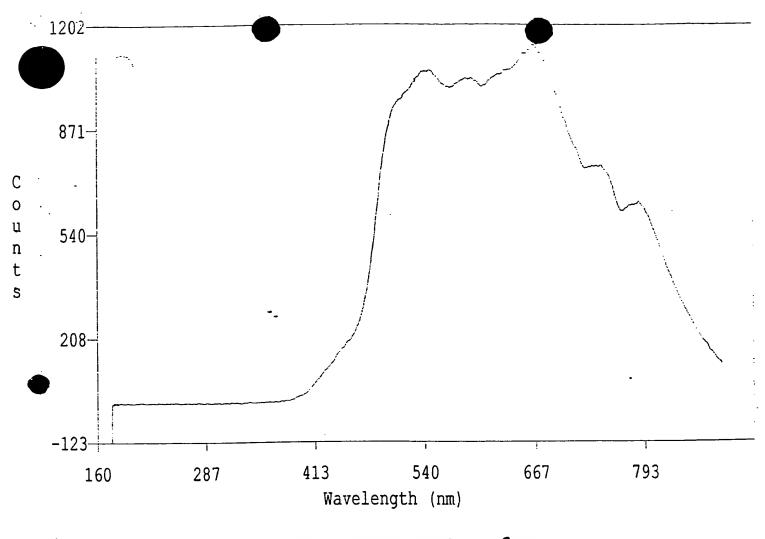
23 20. The method of claim 19, in which the or each 24 dopant is formed by fusion melting before 25 micronising.

26

27 21. The method of claim 20, in which the fusion 28 melting is of silicates, phosphates or borates.

29

30



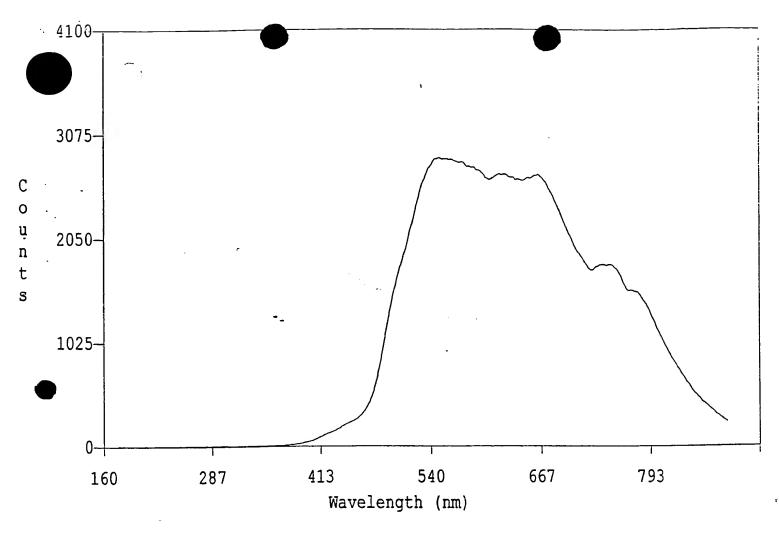
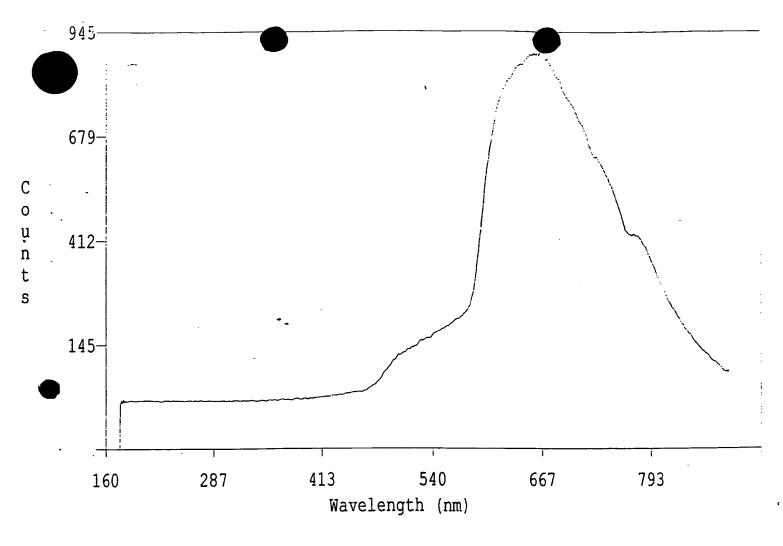
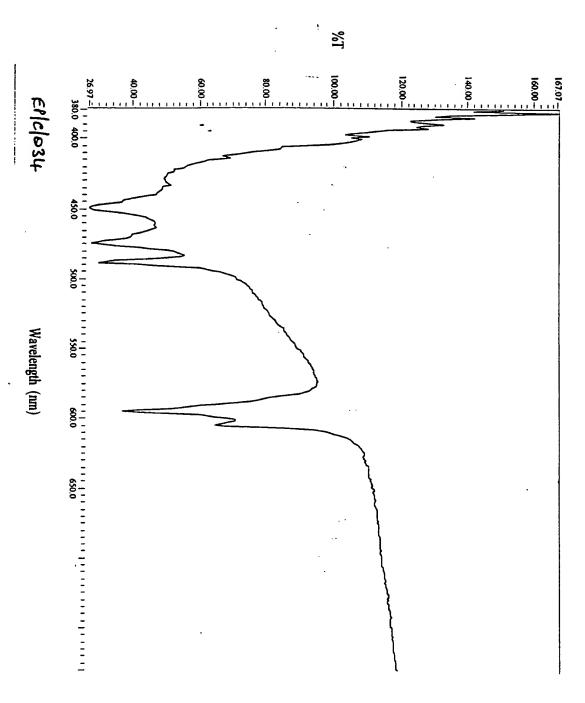
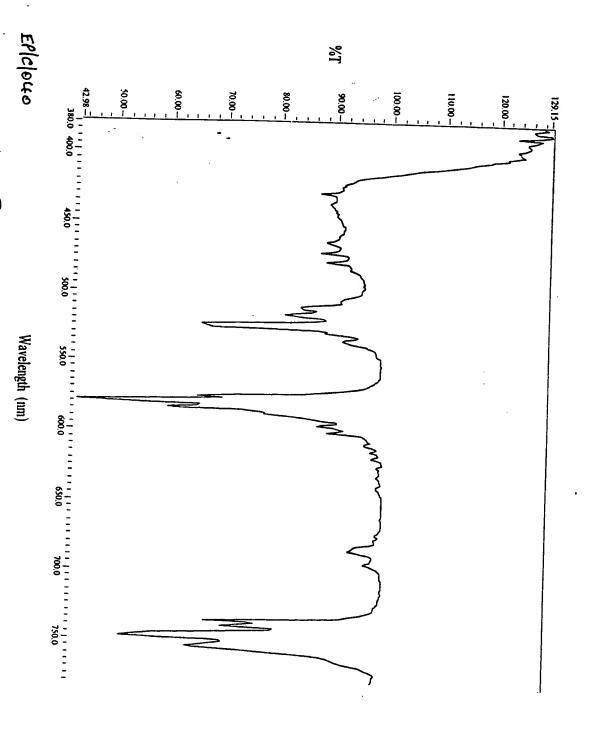


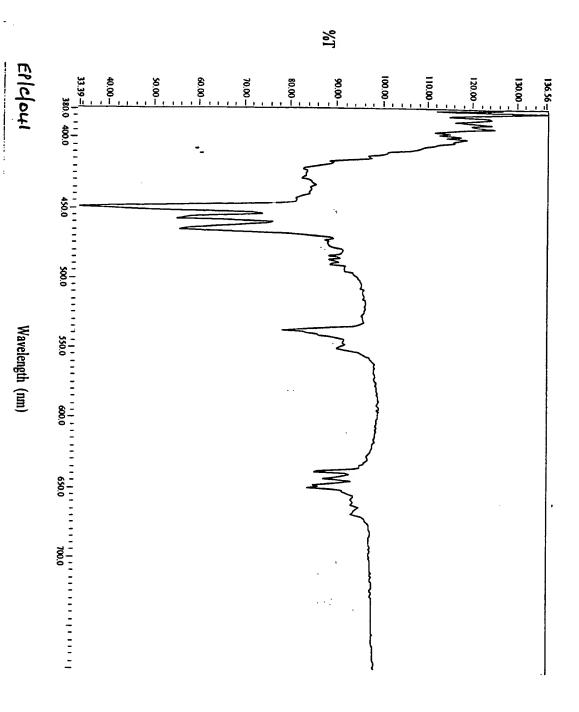
FIG 2 BREEN INK REFLECTANCE SPECTRUM

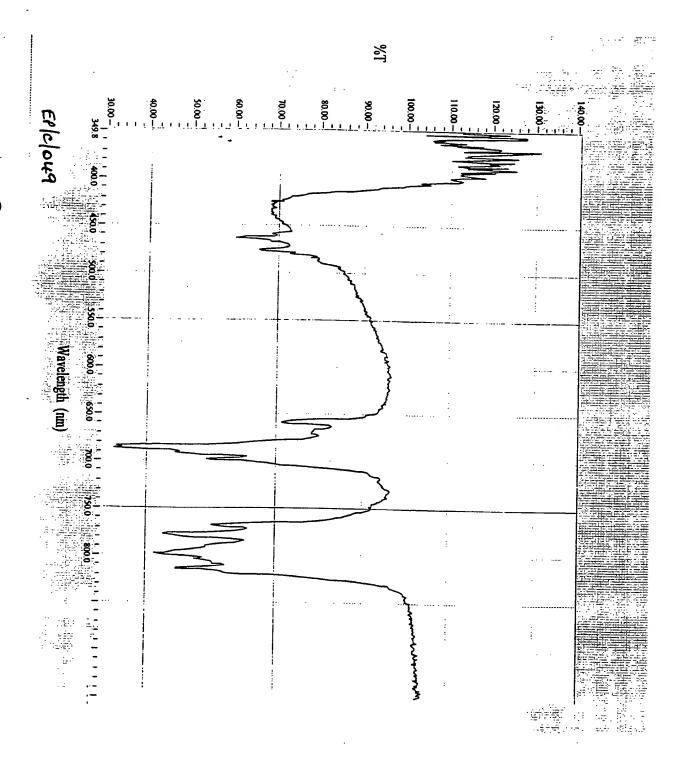


963: RED INE REFLECTANCE SPECTRUM







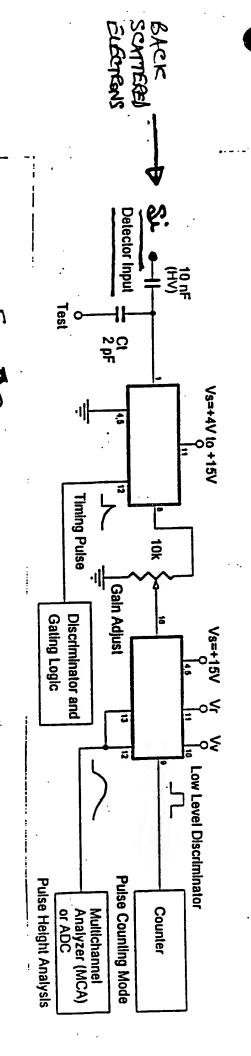


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APROX 4" EXCITATION, ELECTRON CONERT BORANT 2 SUB-MICRON DETECTIVE: HEAD BACKSEAMERED ELECTRONS, OR DUORESCENCE K-RAYS SIGNAL, IMER/PLASTIC BOKED OBJECT posses surpries of PROCESSIME ELECTIONICS FLECTESNICS, 300 State HOUSING! THICKLY MASTIC SEMICIRCULAR PELEGIBE SONIECE

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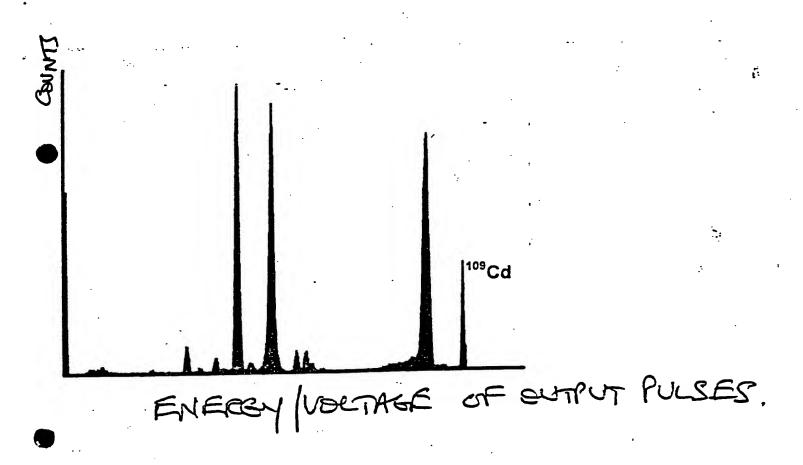


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TYPICAL ELECTRON NETECTOR CIRCUITRY

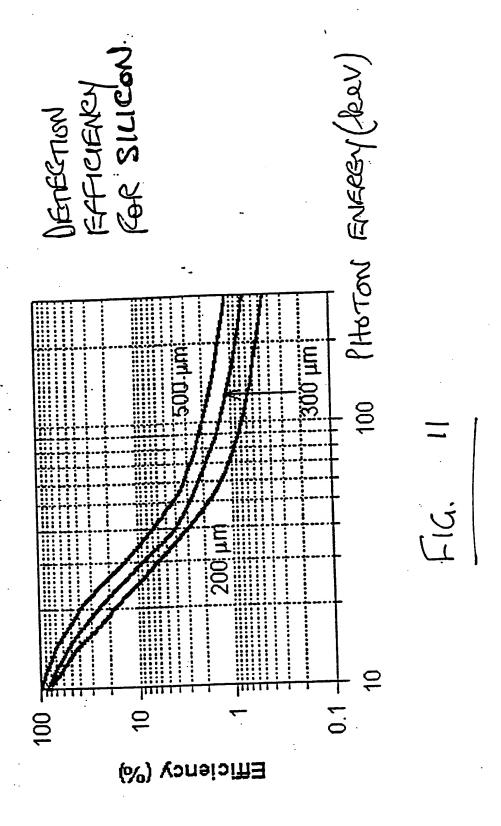
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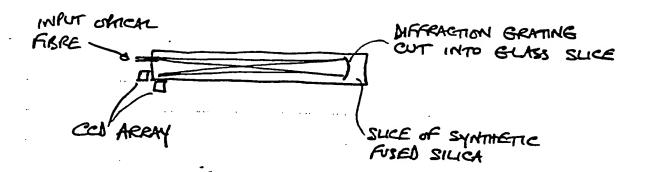
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## SIGE VIEW



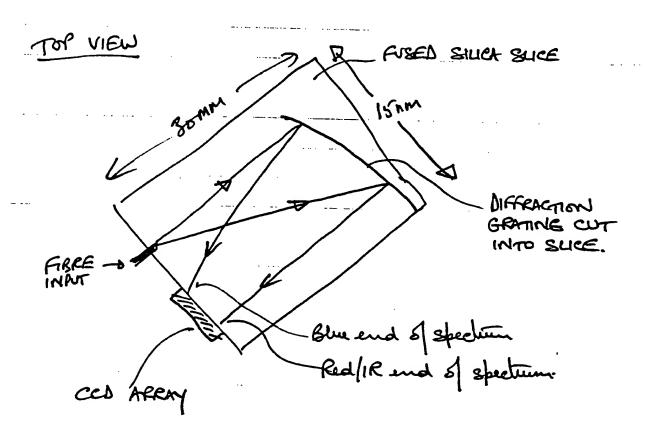


FIG 12 Shetch of frinciple of glass slice spectrometer.

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